

### FEATURES

- RF frequency range of 1200 MHz to 2500 MHz
- IF frequency range of 30 MHz to 450 MHz
- Power conversion gain: 8.4 dB
- SSB noise figure of 9.2 dB
- SSB noise figure with 5 dBm blocker of 20 dB
- Input IP3 of 27 dBm
- Input P1dB of 10.4 dBm
- Typical LO drive of 0 dBm
- Single-ended, 50  $\Omega$  RF and LO input ports
- High isolation SPDT LO input switch
- Single-supply operation: 3.3 V to 5 V
- Exposed paddle 5 mm  $\times$  5 mm, 20-lead LFCSP
- 1500 V HBM/500 V FICDM ESD performance

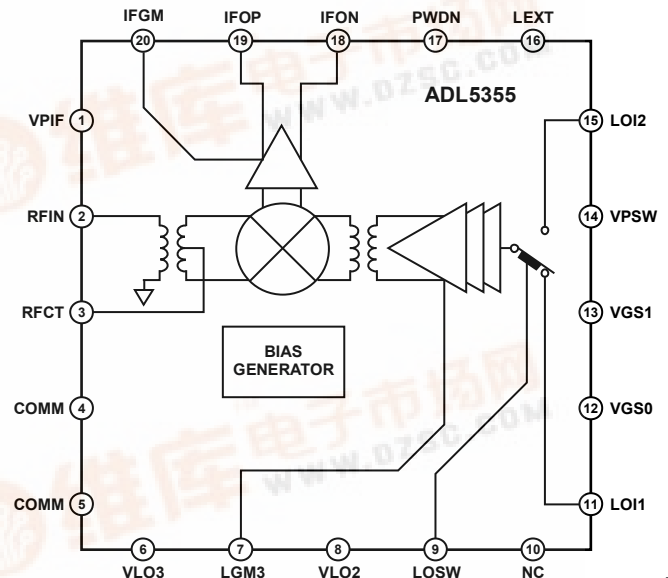
### APPLICATIONS

- Cellular base station receivers
- Transmit observation receivers
- Radio link downconverters

### GENERAL DESCRIPTION

The ADL5355 uses a highly linear, doubly balanced passive mixer core along with integrated RF and LO balancing circuitry to allow for single-ended operation. The ADL5355 incorporates an RF balun, allowing for optimal performance over a 1200 MHz to 2500 MHz RF input frequency range using low-side LO injection for RF frequencies from 1700 MHz to 2500 MHz and high-side LO injection for RF frequencies from 1200 MHz to 1700 MHz. The balanced passive mixer arrangement provides good LO-to-RF leakage, typically better than  $-39$  dBm, and excellent intermodulation performance. The balanced mixer core also provides extremely high input linearity, allowing the device to be used in demanding cellular applications where in-band blocking signals may otherwise result in the degradation of dynamic performance. A high linearity IF buffer amplifier follows the passive mixer core to yield a typical power conversion gain of 8.4 dB and can be used with a wide range of output impedances.

### FUNCTIONAL BLOCK DIAGRAM



NC = NO CONNECT

Figure 1.

The ADL5355 provides two switched LO paths that can be used in TDD applications where it is desirable to rapidly switch between two local oscillators. LO current can be externally set using a resistor to minimize dc current commensurate with the desired level of performance. For low voltage applications, the ADL5355 is capable of operation at voltages down to 3.3 V with substantially reduced current. Under low voltage operation, an additional logic pin is provided to power down ( $<200 \mu\text{A}$ ) the circuit when desired.

The ADL5355 is fabricated using a BiCMOS high performance IC process. The device is available in a 5 mm  $\times$  5 mm, 20-lead LFCSP and operates over a  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$  temperature range. An evaluation board is also available.

Rev. 0

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## REVISION HISTORY

7/09—Revision 0: Initial Version

## SPECIFICATIONS

$V_S = 5\text{ V}$ ,  $I_S = 190\text{ mA}$ ,  $T_A = 25^\circ\text{C}$ ,  $f_{RF} = 1950\text{ MHz}$ ,  $f_{LO} = 1750\text{ MHz}$ , LO power = 0 dBm,  $Z_O = 50\ \Omega$ , unless otherwise noted.

Table 1.

| Parameter                                | Conditions                                                                                    | Min  | Typ       | Max  | Unit                |
|------------------------------------------|-----------------------------------------------------------------------------------------------|------|-----------|------|---------------------|
| RF INPUT INTERFACE                       |                                                                                               |      |           |      |                     |
| Return Loss                              | Tunable to >20 dB over a limited bandwidth                                                    |      | 20        |      | dB                  |
| Input Impedance                          |                                                                                               |      | 50        |      | $\Omega$            |
| RF Frequency Range                       |                                                                                               | 1200 |           | 2500 | MHz                 |
| OUTPUT INTERFACE                         |                                                                                               |      |           |      |                     |
| Output Impedance                         | Differential impedance, $f = 200\text{ MHz}$                                                  |      | 230  0.75 |      | $\Omega  \text{pF}$ |
| IF Frequency Range                       | Externally generated                                                                          | 30   |           | 450  | MHz                 |
| DC Bias Voltage <sup>1</sup>             |                                                                                               | 3.3  | 5.0       | 5.5  | V                   |
| LO INTERFACE                             |                                                                                               |      |           |      |                     |
| LO Power                                 |                                                                                               | -6   | 0         | +10  | dBm                 |
| Return Loss                              |                                                                                               |      | 15        |      | dB                  |
| Input Impedance                          |                                                                                               |      | 50        |      | $\Omega$            |
| LO Frequency Range                       |                                                                                               | 1230 |           | 2470 | MHz                 |
| POWER-DOWN (PWDN) INTERFACE <sup>2</sup> |                                                                                               |      |           |      |                     |
| PWDN Threshold                           | Device enabled, IF output to 90% of its final level<br>Device disabled, supply current < 5 mA |      | 1.0       |      | V                   |
| Logic 0 Level                            |                                                                                               |      |           | 0.4  | V                   |
| Logic 1 Level                            |                                                                                               | 1.4  |           |      | V                   |
| PWDN Response Time                       |                                                                                               |      | 160       |      | ns                  |
|                                          |                                                                                               |      | 220       |      | ns                  |
| PWDN Input Bias Current                  | Device enabled                                                                                |      | 0.0       |      | $\mu\text{A}$       |
|                                          | Device disabled                                                                               |      | 70        |      | $\mu\text{A}$       |

<sup>1</sup> Apply the supply voltage from the external circuit through the choke inductors.

<sup>2</sup> PWDN function is intended for use with  $V_S \leq 3.6\text{ V}$  only.

**5 V PERFORMANCE**

$V_S = 5\text{ V}$ ,  $I_S = 190\text{ mA}$ ,  $T_A = 25^\circ\text{C}$ ,  $f_{RF} = 1950\text{ MHz}$ ,  $f_{LO} = 1750\text{ MHz}$ , LO power = 0 dBm, VGS0 = VGS1 = 0 V, and  $Z_O = 50\ \Omega$ , unless otherwise noted.

**Table 2.**

| Parameter                            | Conditions                                                                                                                    | Min | Typ     | Max | Unit |
|--------------------------------------|-------------------------------------------------------------------------------------------------------------------------------|-----|---------|-----|------|
| <b>DYNAMIC PERFORMANCE</b>           |                                                                                                                               |     |         |     |      |
| Power Conversion Gain                | Including 4:1 IF port transformer and PCB loss                                                                                | 7   | 8.4     | 9.5 | dB   |
| Voltage Conversion Gain              | $Z_{SOURCE} = 50\ \Omega$ , differential $Z_{LOAD} = 200\ \Omega$ differential                                                |     | 14.7    |     | dB   |
| SSB Noise Figure                     |                                                                                                                               |     | 9.2     |     | dB   |
| SSB Noise Figure Under Blocking      | 5 dBm blocker present $\pm 10\text{ MHz}$ from wanted RF input, LO source filtered                                            |     | 20      |     | dB   |
| Input Third-Order Intercept (IIP3)   | $f_{RF1} = 1949.5\text{ MHz}$ , $f_{RF2} = 1950.5\text{ MHz}$ , $f_{LO} = 1750\text{ MHz}$ , each RF tone at $-10\text{ dBm}$ | 22  | 27      |     | dBm  |
| Input Second-Order Intercept (IIP2)  | $f_{RF1} = 1950\text{ MHz}$ , $f_{RF2} = 1900\text{ MHz}$ , $f_{LO} = 1750\text{ MHz}$ , each RF tone at $-10\text{ dBm}$     |     | 50      |     | dBm  |
| Input 1 dB Compression Point (IP1dB) |                                                                                                                               |     | 10.4    |     | dBm  |
| LO-to-IF Leakage                     | Unfiltered IF output                                                                                                          |     | $-12.6$ |     | dBm  |
| LO-to-RF Leakage                     |                                                                                                                               |     | $-39$   |     | dBm  |
| RF-to-IF Isolation                   |                                                                                                                               |     | $-33$   |     | dBc  |
| IF/2 Spurious                        | $-10\text{ dBm}$ input power                                                                                                  |     | $-69$   |     | dBc  |
| IF/3 Spurious                        | $-10\text{ dBm}$ input power                                                                                                  |     | $-73$   |     | dBc  |
| <b>POWER SUPPLY</b>                  |                                                                                                                               |     |         |     |      |
| Positive Supply Voltage              |                                                                                                                               | 4.5 | 5       | 5.5 | V    |
| Quiescent Current                    | LO supply, resistor programmable                                                                                              |     | 100     |     | mA   |
|                                      | IF supply, resistor programmable                                                                                              |     | 90      |     | mA   |
| Total Quiescent Current              | $V_S = 5\text{ V}$                                                                                                            |     | 190     |     | mA   |

**3.3 V PERFORMANCE**

$V_S = 3.3\text{ V}$ ,  $I_S = 125\text{ mA}$ ,  $T_A = 25^\circ\text{C}$ ,  $f_{RF} = 1950\text{ MHz}$ ,  $f_{LO} = 1750\text{ MHz}$ , LO power = 0 dBm, R9 = 226  $\Omega$ , R14 = 604  $\Omega$ , VGS0 = VGS1 = 0 V, and  $Z_O = 50\ \Omega$ , unless otherwise noted.

**Table 3.**

| Parameter                            | Conditions                                                                                                                    | Min | Typ  | Max | Unit          |
|--------------------------------------|-------------------------------------------------------------------------------------------------------------------------------|-----|------|-----|---------------|
| <b>DYNAMIC PERFORMANCE</b>           |                                                                                                                               |     |      |     |               |
| Power Conversion Gain                | Including 4:1 IF port transformer and PCB loss                                                                                |     | 9    |     | dB            |
| Voltage Conversion Gain              | $Z_{SOURCE} = 50\ \Omega$ , differential $Z_{LOAD} = 200\ \Omega$ differential                                                |     | 15.3 |     | dB            |
| SSB Noise Figure                     |                                                                                                                               |     | 8.75 |     | dB            |
| Input Third-Order Intercept (IIP3)   | $f_{RF1} = 1949.5\text{ MHz}$ , $f_{RF2} = 1950.5\text{ MHz}$ , $f_{LO} = 1750\text{ MHz}$ , each RF tone at $-10\text{ dBm}$ |     | 22   |     | dBm           |
| Input Second-Order Intercept (IIP2)  | $f_{RF1} = 1950\text{ MHz}$ , $f_{RF2} = 1900\text{ MHz}$ , $f_{LO} = 1750\text{ MHz}$ , each RF tone at $-10\text{ dBm}$     |     | 52   |     | dBm           |
| Input 1 dB Compression Point (IP1dB) |                                                                                                                               |     | 7    |     | dBm           |
| <b>POWER INTERFACE</b>               |                                                                                                                               |     |      |     |               |
| Supply Voltage                       |                                                                                                                               | 3.0 | 3.3  | 3.6 | V             |
| Quiescent Current                    | Resistor programmable                                                                                                         |     | 125  |     | mA            |
| Power-Down Current                   | Device disabled                                                                                                               |     | 150  |     | $\mu\text{A}$ |

## SPUR TABLES

All spur tables are  $(N \times f_{RF}) - (M \times f_{LO})$  and were measured using the standard evaluation board. Mixer spurious products are measured in dBc from the IF output power level. Data was only measured for frequencies less than 6 GHz. Typical noise floor of the measurement system = -100 dBm.

### 5 V Performance

$V_S = 5\text{ V}$ ,  $I_S = 190\text{ mA}$ ,  $T_A = 25^\circ\text{C}$ ,  $f_{RF} = 1900\text{ MHz}$ ,  $f_{LO} = 1697\text{ MHz}$ , LO power = 0 dBm,  $V_{GS0} = V_{GS1} = 0\text{ V}$ , and  $Z_O = 50\ \Omega$ , unless otherwise noted.

**Table 4.**

|   | M  |       |       |       |       |       |       |       |       |       |       |       |       |       |       |
|---|----|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|
|   | 0  | 1     | 2     | 3     | 4     | 5     | 6     | 7     | 8     | 9     | 10    | 11    | 12    | 13    | 14    |
| N | 0  | -10.0 | -21.1 | -53.8 |       |       |       |       |       |       |       |       |       |       |       |
|   | 1  | -42.3 | 0.0   | -57.1 | -51.4 | -75.9 |       |       |       |       |       |       |       |       |       |
|   | 2  | -66.7 | -65.3 | -57.0 | -67.0 | -88.4 | <-100 |       |       |       |       |       |       |       |       |
|   | 3  | <-100 | <-100 | -97.6 | -61.6 | <-100 | <-100 | <-100 |       |       |       |       |       |       |       |
|   | 4  |       | <-100 | <-100 | <-100 | -97.9 | <-100 | <-100 | <-100 | <-100 |       |       |       |       |       |
|   | 5  |       |       |       | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 |       |       |       |       |
|   | 6  |       |       |       |       | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 |       |       |       |
|   | 7  |       |       |       |       |       | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 |       |       |
|   | 8  |       |       |       |       |       |       | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 |       |
|   | 9  |       |       |       |       |       |       |       | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 |
|   | 10 |       |       |       |       |       |       |       |       | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 |
|   | 11 |       |       |       |       |       |       |       |       |       | <-100 | <-100 | <-100 | <-100 | <-100 |
|   | 12 |       |       |       |       |       |       |       |       |       |       | <-100 | <-100 | <-100 | <-100 |
|   | 13 |       |       |       |       |       |       |       |       |       |       |       |       | <-100 | <-100 |
|   | 14 |       |       |       |       |       |       |       |       |       |       |       |       |       | <-100 |
|   | 15 |       |       |       |       |       |       |       |       |       |       |       |       |       | <-100 |

### 3.3 V Performance

$V_S = 3.3\text{ V}$ ,  $I_S = 125\text{ mA}$ ,  $T_A = 25^\circ\text{C}$ ,  $f_{RF} = 1900\text{ MHz}$ ,  $f_{LO} = 1697\text{ MHz}$ , LO power = 0 dBm,  $R_9 = 226\ \Omega$ ,  $R_{14} = 604\ \Omega$ ,  $V_{GS0} = V_{GS1} = 0\text{ V}$ , and  $Z_O = 50\ \Omega$ , unless otherwise noted.

**Table 5.**

|   | M  |       |       |       |       |       |       |       |       |       |       |       |       |       |       |
|---|----|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|
|   | 0  | 1     | 2     | 3     | 4     | 5     | 6     | 7     | 8     | 9     | 10    | 11    | 12    | 13    | 14    |
| N | 0  | -15.3 | -27.3 | -65.5 |       |       |       |       |       |       |       |       |       |       |       |
|   | 1  | -42.9 | 0.0   | -58.3 | -52.2 | -78.0 |       |       |       |       |       |       |       |       |       |
|   | 2  | -64.4 | -67.3 | -56.6 | -73.6 | -75.7 | <-100 |       |       |       |       |       |       |       |       |
|   | 3  | <-100 | <-100 | -95.5 | -60.4 | <-100 | <-100 | <-100 |       |       |       |       |       |       |       |
|   | 4  |       | <-100 | <-100 | <-100 | -97.0 | <-100 | <-100 | <-100 | <-100 |       |       |       |       |       |
|   | 5  |       |       |       | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 |       |       |       |       |
|   | 6  |       |       |       |       | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 |       |       |       |
|   | 7  |       |       |       |       |       | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 |       |       |
|   | 8  |       |       |       |       |       |       | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 |       |
|   | 9  |       |       |       |       |       |       |       | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 |
|   | 10 |       |       |       |       |       |       |       |       | <-100 | <-100 | <-100 | <-100 | <-100 | <-100 |
|   | 11 |       |       |       |       |       |       |       |       |       | <-100 | <-100 | <-100 | <-100 | <-100 |
|   | 12 |       |       |       |       |       |       |       |       |       |       | <-100 | <-100 | <-100 | <-100 |
|   | 13 |       |       |       |       |       |       |       |       |       |       |       |       | <-100 | <-100 |
|   | 14 |       |       |       |       |       |       |       |       |       |       |       |       |       | <-100 |
|   | 15 |       |       |       |       |       |       |       |       |       |       |       |       |       | <-100 |

## ABSOLUTE MAXIMUM RATINGS

Table 6.

| Parameter                                  | Rating          |
|--------------------------------------------|-----------------|
| Supply Voltage, $V_S$                      | 5.5 V           |
| RF Input Level                             | 20 dBm          |
| LO Input Level                             | 13 dBm          |
| IFOP, IFON Bias Voltage                    | 6.0 V           |
| VGS0, VGS1, LOSW, PWDN                     | 5.5 V           |
| Internal Power Dissipation                 | 1.2 W           |
| $\theta_{JA}$                              | 25°C/W          |
| Maximum Junction Temperature               | 150°C           |
| Operating Temperature Range                | –40°C to +85°C  |
| Storage Temperature Range                  | –65°C to +150°C |
| Lead Temperature Range (Soldering, 60 sec) | 260°C           |

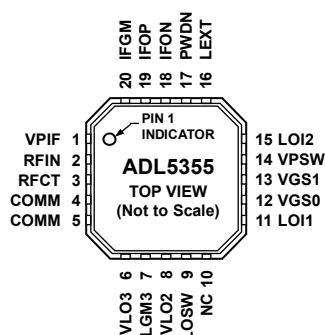
Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### ESD CAUTION



**ESD (electrostatic discharge) sensitive device.** Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## PIN CONFIGURATION AND FUNCTION DESCRIPTIONS



**NOTES**  
1. NC = NO CONNECT.  
2. EXPOSED PAD. MUST BE SOLDERED TO GROUND.

080800-002

Figure 2. Pin Configuration

Table 7. Pin Function Descriptions

| Pin No. | Mnemonic   | Description                                                                                                 |
|---------|------------|-------------------------------------------------------------------------------------------------------------|
| 1       | VPIF       | Positive Supply Voltage for IF Amplifier.                                                                   |
| 2       | RFIN       | RF Input. Must be ac-coupled.                                                                               |
| 3       | RFCT       | RF Balun Center Tap (AC Ground).                                                                            |
| 4, 5    | COMM       | Device Common (DC Ground).                                                                                  |
| 6, 8    | VLO3, VLO2 | Positive Supply Voltages for LO Amplifier.                                                                  |
| 7       | LGM3       | LO Amplifier Bias Control.                                                                                  |
| 9       | LOSW       | LO Switch. LOI1 selected for 0 V, and LOI2 selected for 3 V.                                                |
| 10      | NC         | No Connect.                                                                                                 |
| 11, 15  | LOI1, LOI2 | LO Inputs. Must be ac-coupled.                                                                              |
| 12, 13  | VGS0, VGS1 | Mixer Gate Bias Controls. 3 V logic. Ground these pins for nominal setting.                                 |
| 14      | VPSW       | Positive Supply Voltage for LO Switch.                                                                      |
| 16      | LEXT       | IF Return. This pin must be grounded.                                                                       |
| 17      | PWDN       | Power Down. Connect this pin to ground for normal operation and connect this pin to 3.0 V for disable mode. |
| 18, 19  | IFON, IFOP | Differential IF Outputs (Open Collectors). Each requires an external dc bias.                               |
| 20      | IFGM       | IF Amplifier Bias Control.                                                                                  |
|         | EPAD (EP)  | Exposed pad. Must be soldered to ground.                                                                    |

# TYPICAL PERFORMANCE CHARACTERISTICS

## 5 V PERFORMANCE

$V_S = 5\text{ V}$ ,  $I_S = 190\text{ mA}$ ,  $T_A = 25^\circ\text{C}$ ,  $f_{RF} = 1950\text{ MHz}$ ,  $f_{LO} = 1750\text{ MHz}$ , LO power = 0 dBm,  $R_9 = 1.1\text{ k}\Omega$ ,  $R_{14} = 910\ \Omega$ ,  $V_{GS0} = V_{GS1} = 0\text{ V}$ , and  $Z_O = 50\ \Omega$ , unless otherwise noted.

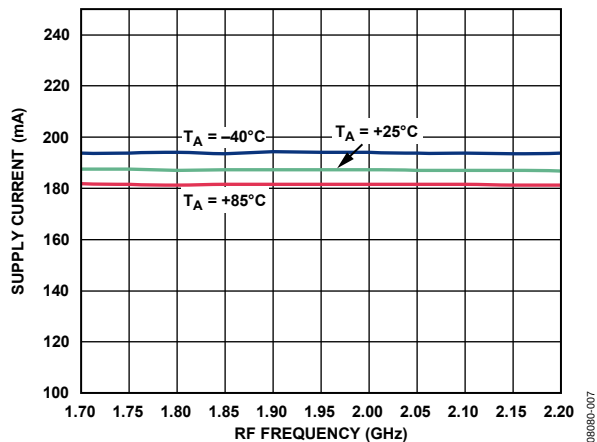


Figure 3. Supply Current vs. RF Frequency

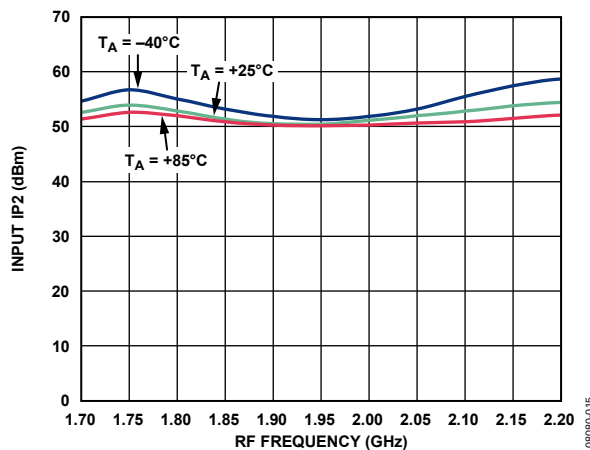


Figure 6. Input IP2 vs. RF Frequency

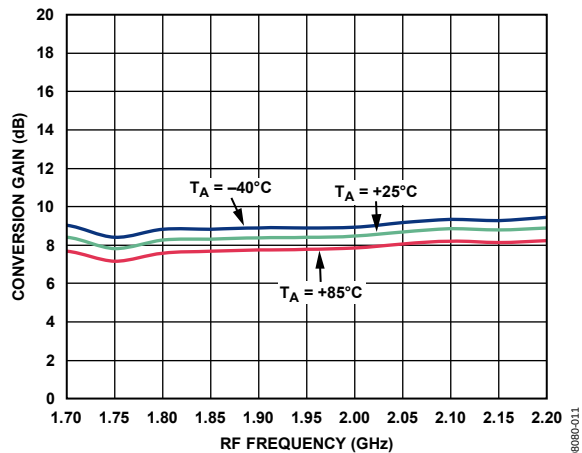


Figure 4. Power Conversion Gain vs. RF Frequency

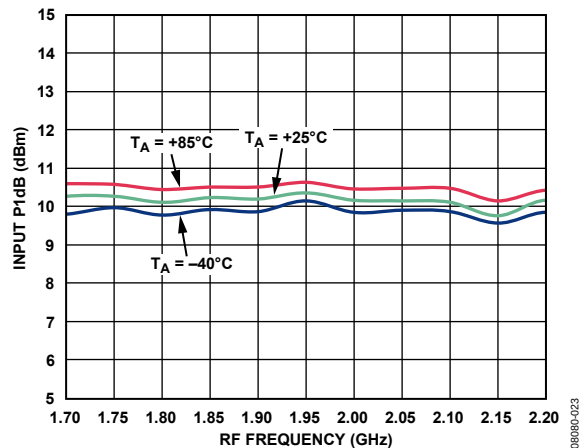


Figure 7. Input P1dB vs. RF Frequency

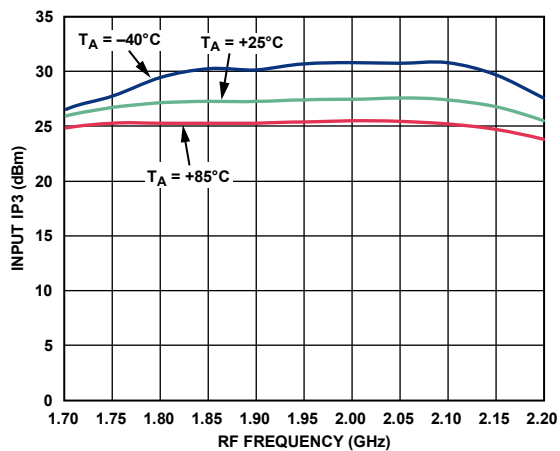


Figure 5. Input IP3 vs. RF Frequency

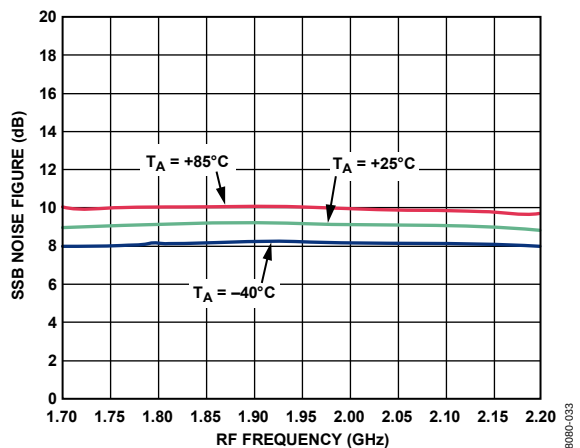


Figure 8. SSB Noise Figure vs. RF Frequency



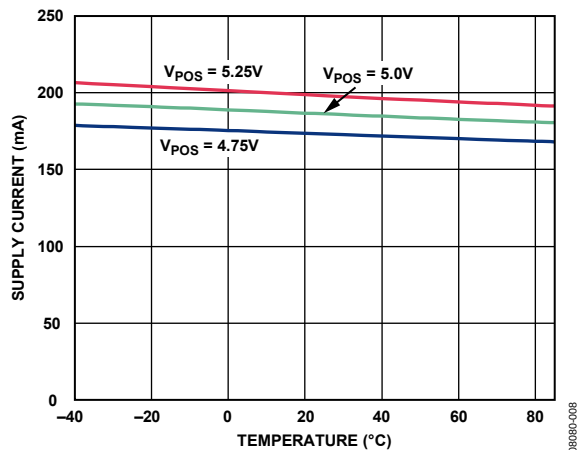


Figure 9. Supply Current vs. Temperature

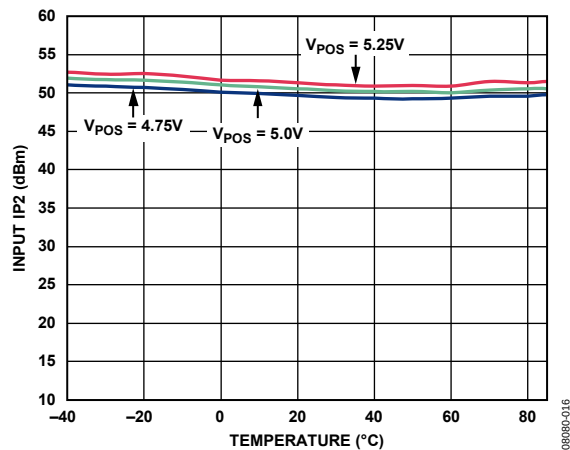


Figure 12. Input IP2 vs. Temperature

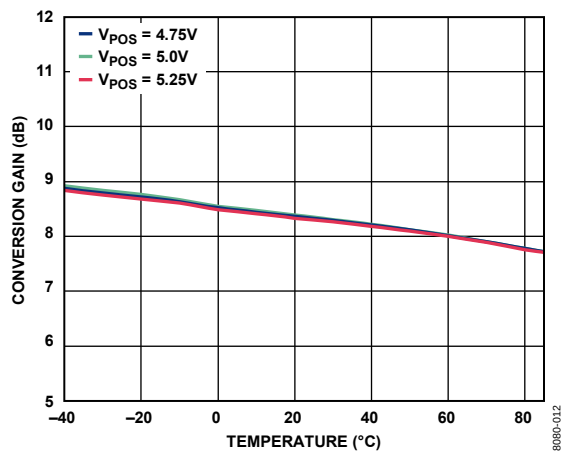


Figure 10. Power Conversion Gain vs. Temperature

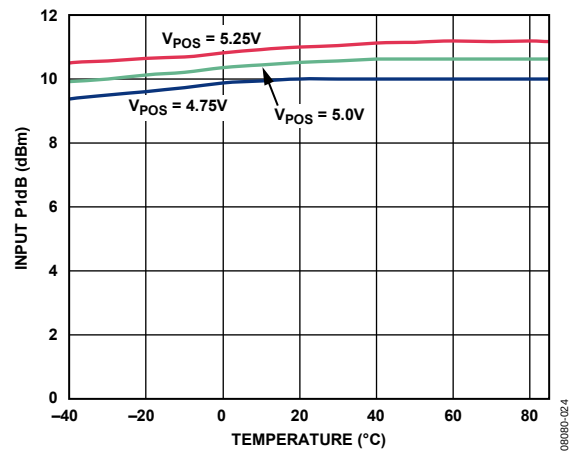


Figure 13. Input P1dB vs. Temperature

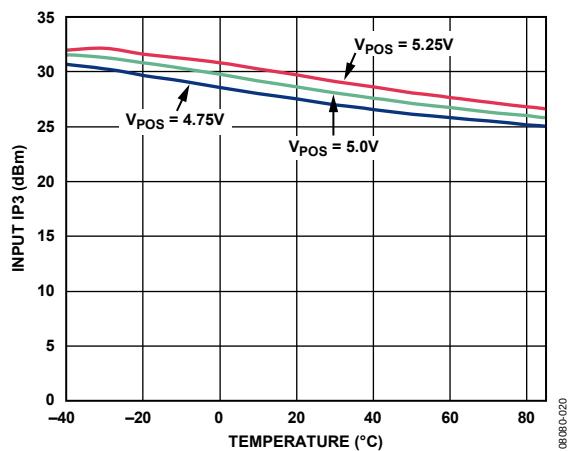


Figure 11. Input IP3 vs. Temperature

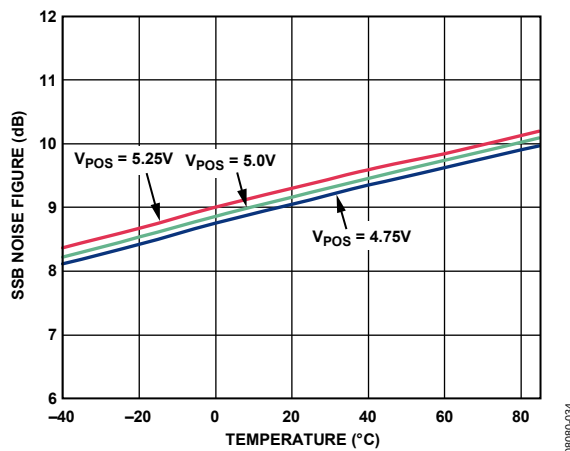


Figure 14. SSB Noise Figure vs. Temperature

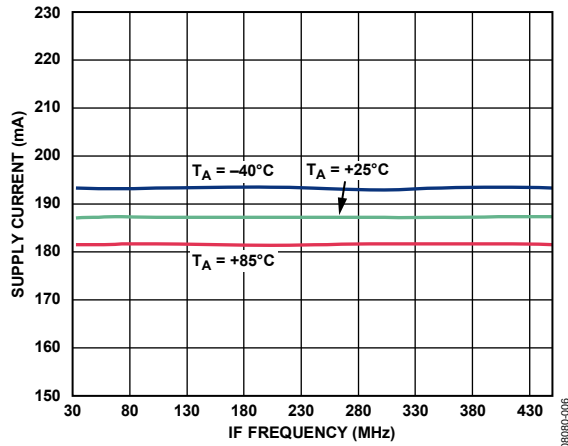


Figure 15. Supply Current vs. IF Frequency

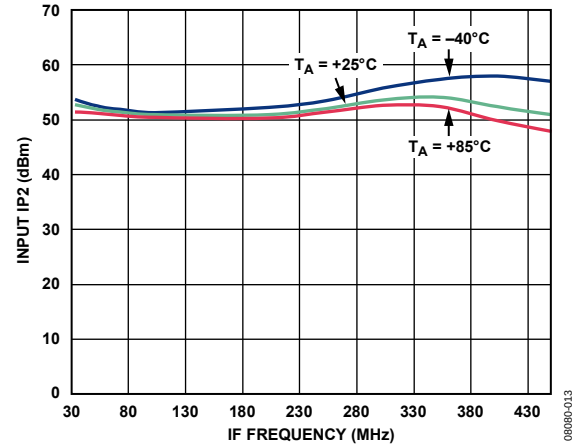


Figure 18. Input IP2 vs. IF Frequency

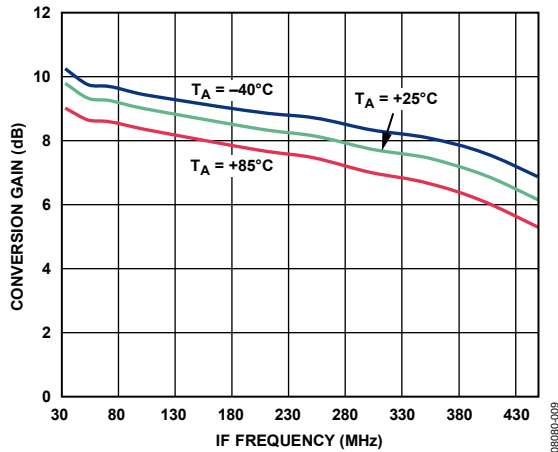


Figure 16. Power Conversion Gain vs. IF Frequency

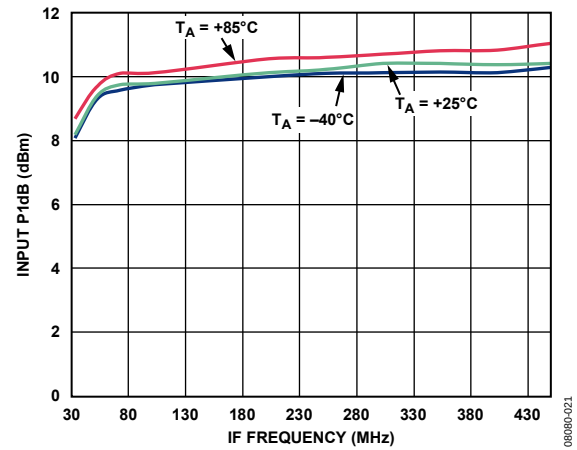


Figure 19. Input P1dB vs. IF Frequency

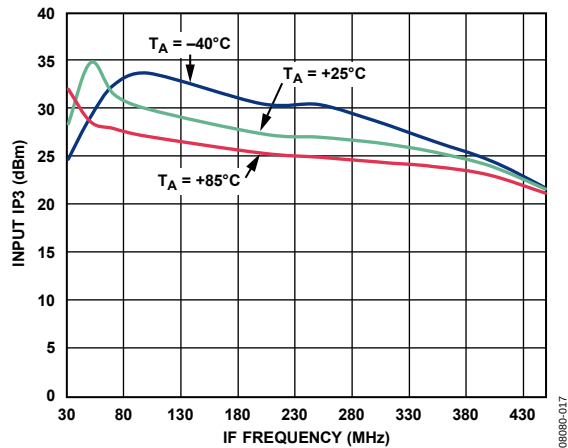


Figure 17. Input IP3 vs. IF Frequency

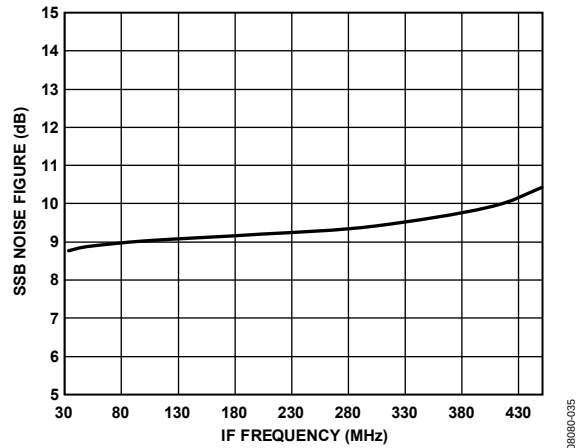


Figure 20. SSB Noise Figure vs. IF Frequency

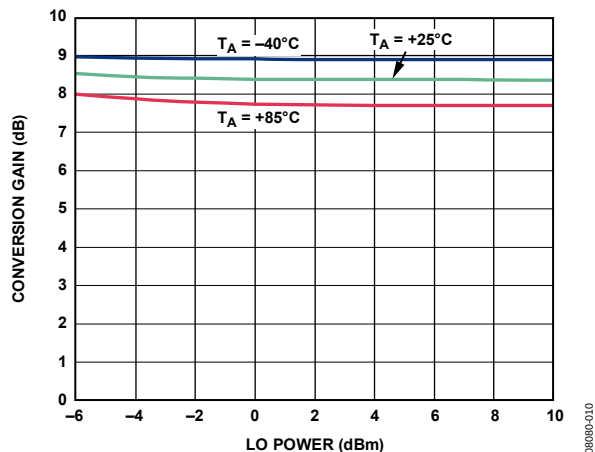


Figure 21. Power Conversion Gain vs. LO Power

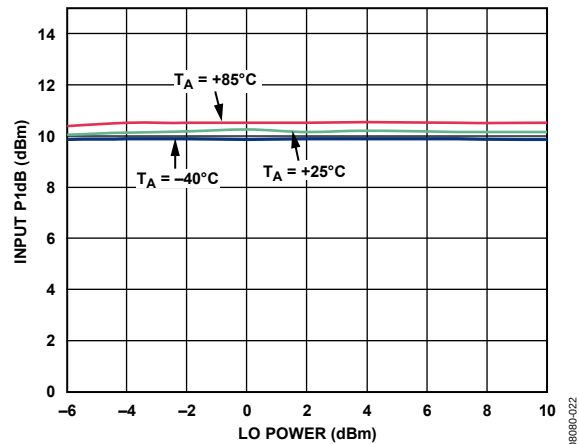


Figure 24. Input P1dB vs. LO Power

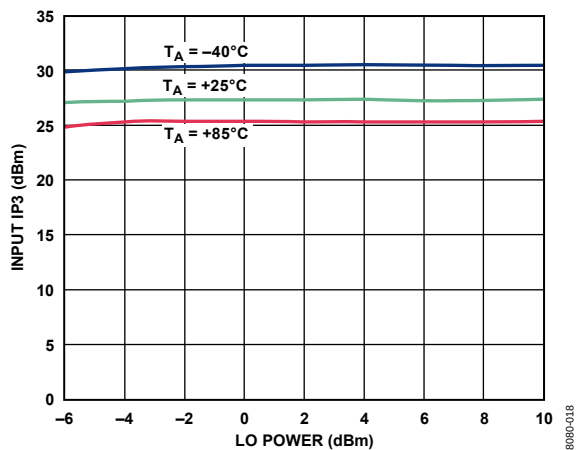


Figure 22. Input IP3 vs. LO Power

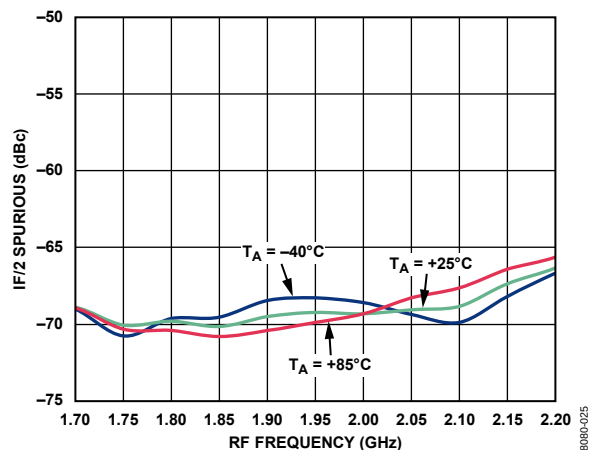


Figure 25. IF/2 Spurious vs. RF Frequency

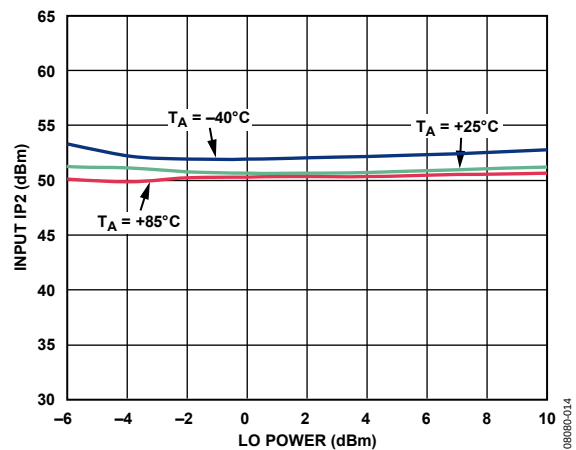


Figure 23. Input IP2 vs. LO Power

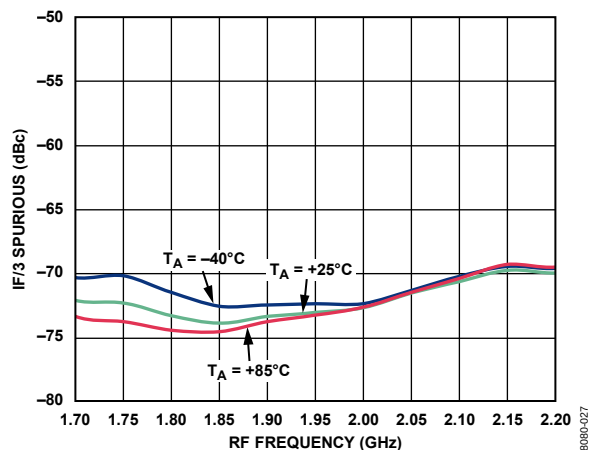


Figure 26. IF/3 Spurious vs. RF Frequency

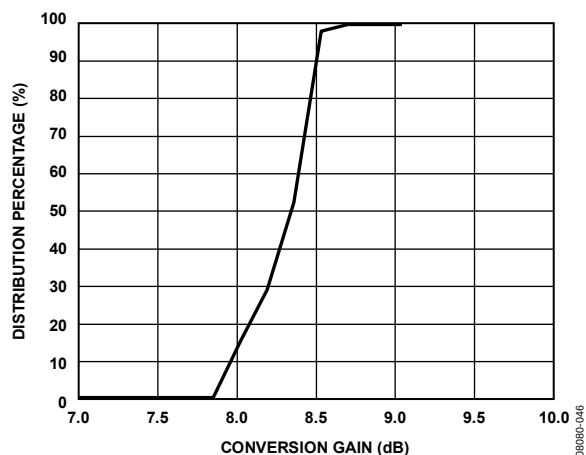


Figure 27. Conversion Gain Distribution

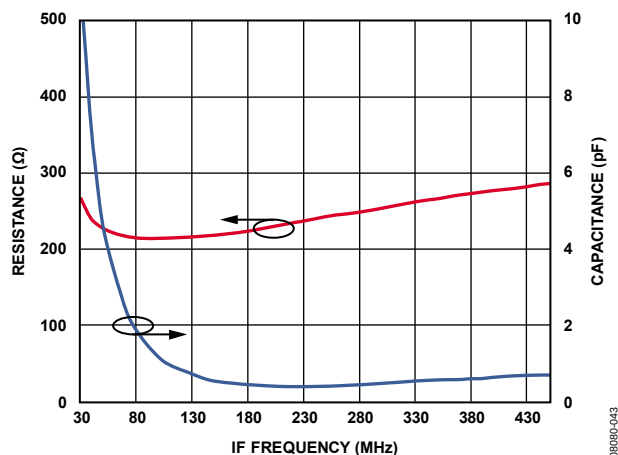


Figure 30. IF Port Return Loss

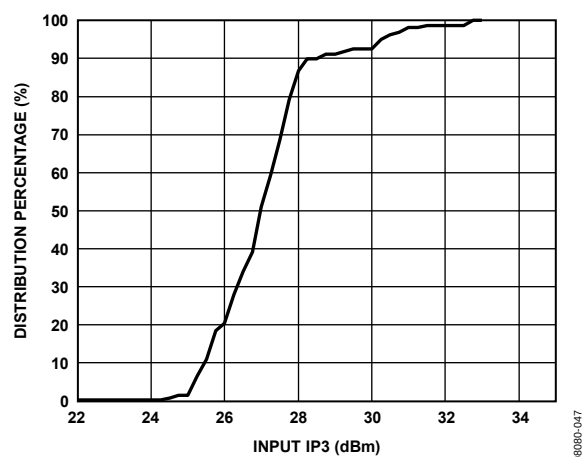


Figure 28. Input IP3 Distribution

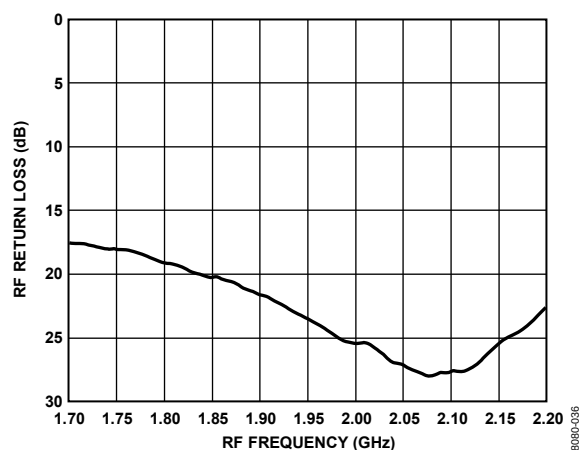


Figure 31. RF Port Return Loss, Fixed IF

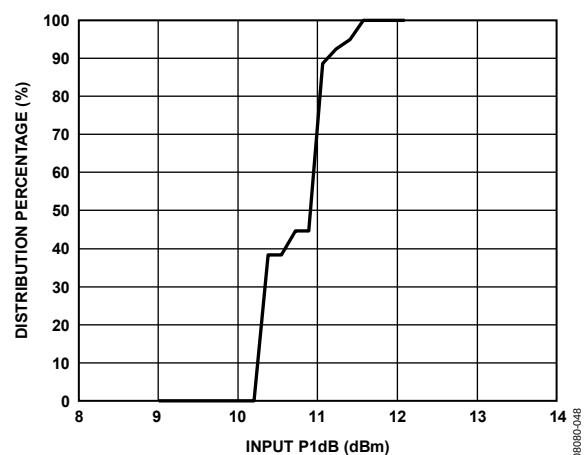


Figure 29. Input P1dB Distribution

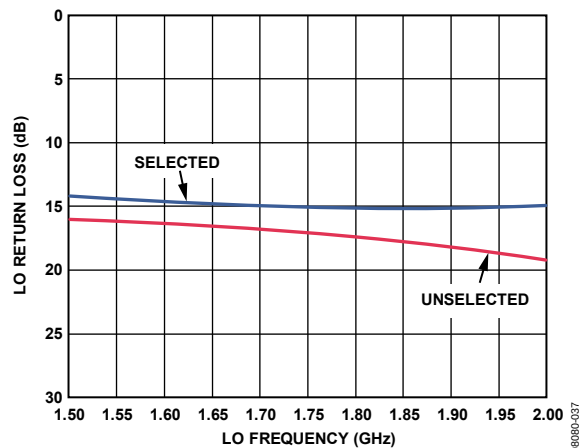


Figure 32. LO Return Loss, Selected and Unselected

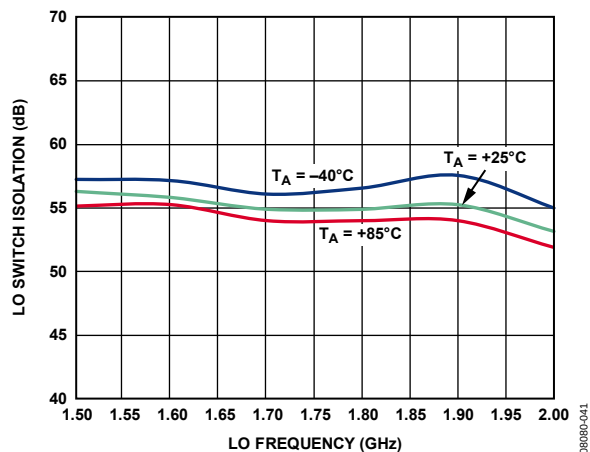


Figure 33. LO Switch Isolation vs. LO Frequency

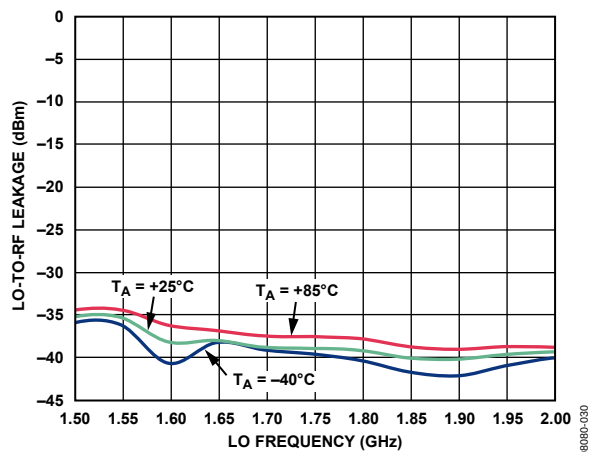


Figure 36. LO-to-RF Leakage vs. LO Frequency

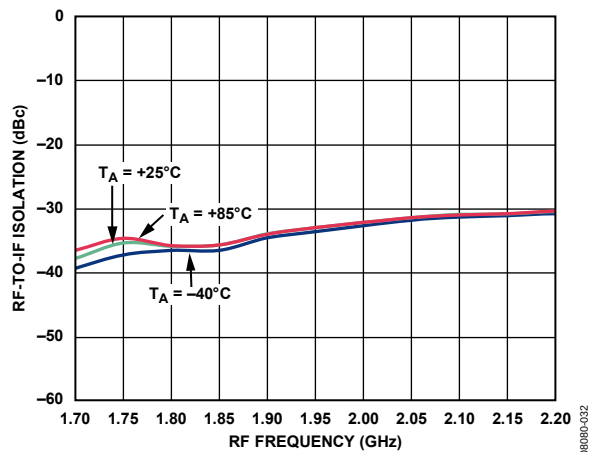


Figure 34. RF-to-IF Isolation vs. RF Frequency

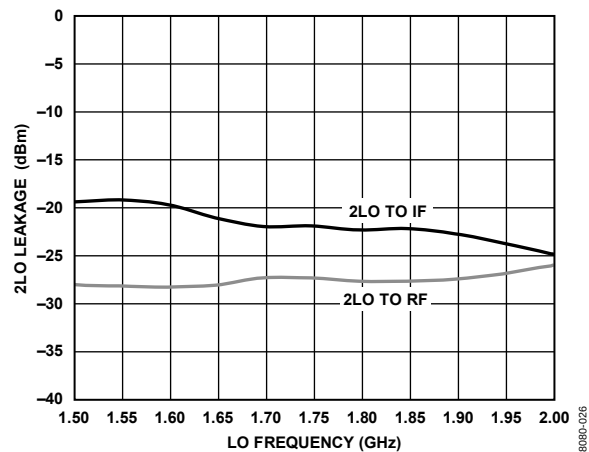


Figure 37. 2LO Leakage vs. LO Frequency

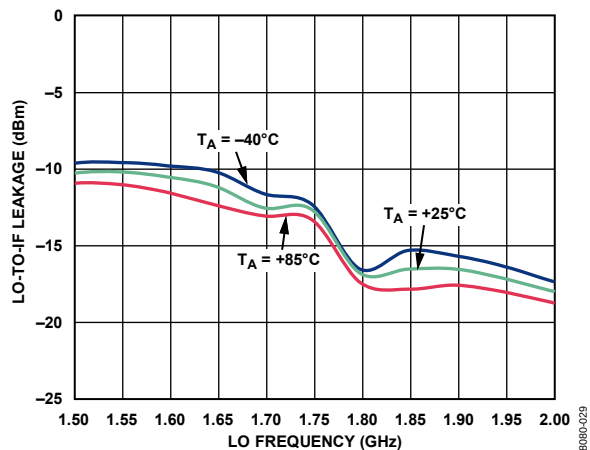


Figure 35. LO-to-IF Leakage vs. LO Frequency

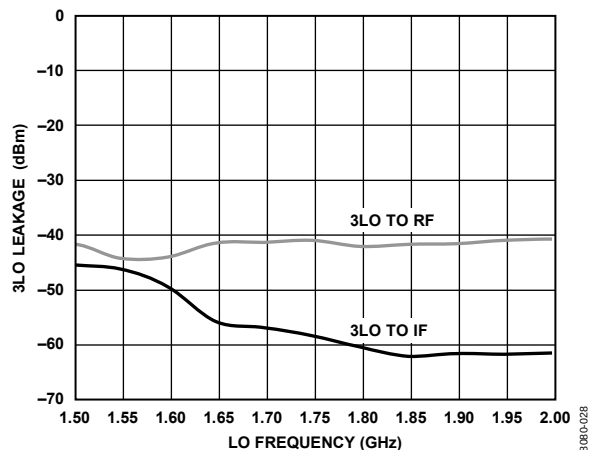


Figure 38. 3LO Leakage vs. LO Frequency

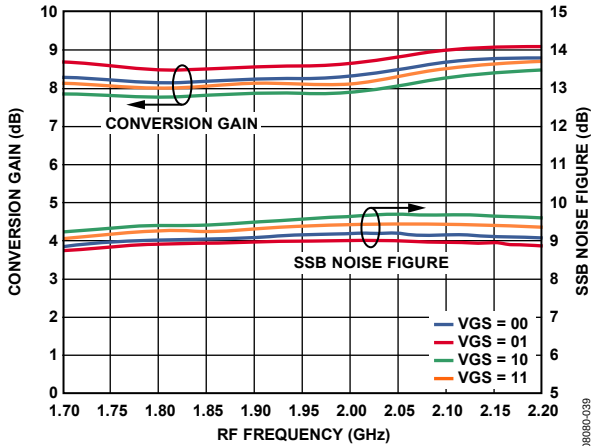


Figure 39. Power Conversion Gain and SSB Noise Figure vs. RF Frequency

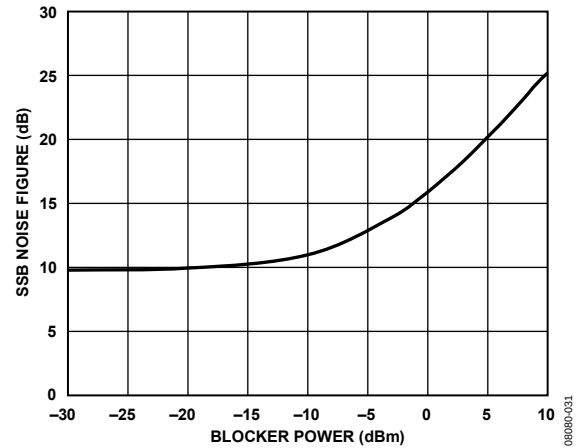


Figure 42. SSB Noise Figure vs. 10 MHz Offset Blocker Level

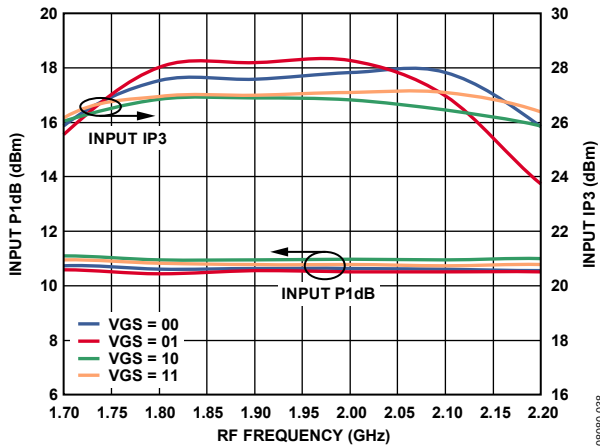


Figure 40. Input IP3 and Input P1dB vs. RF Frequency

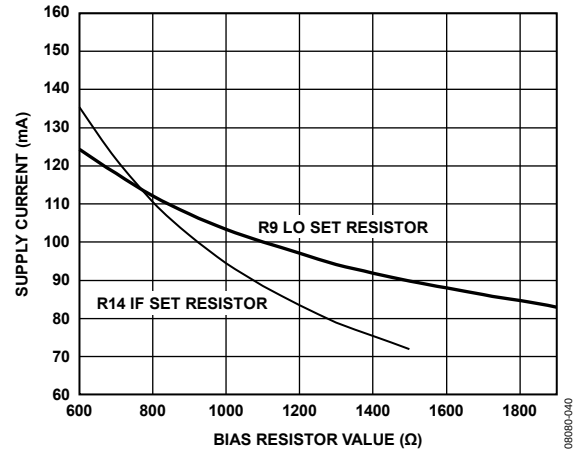


Figure 43. LO and IF Supply Current vs. IF and LO Bias Resistor Value

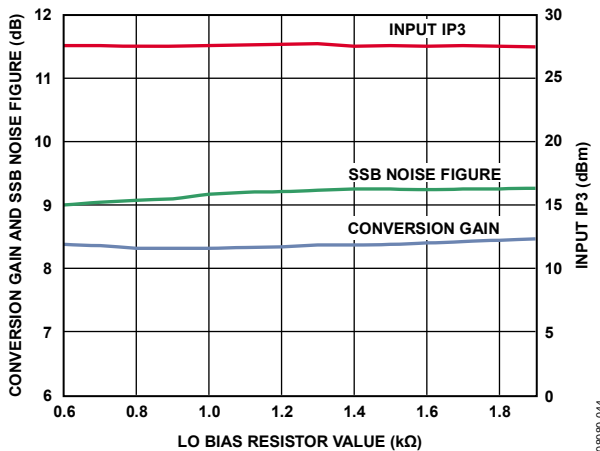


Figure 41. Power Conversion Gain, SSB Noise Figure, and Input IP3 vs. LO Bias Resistor Value

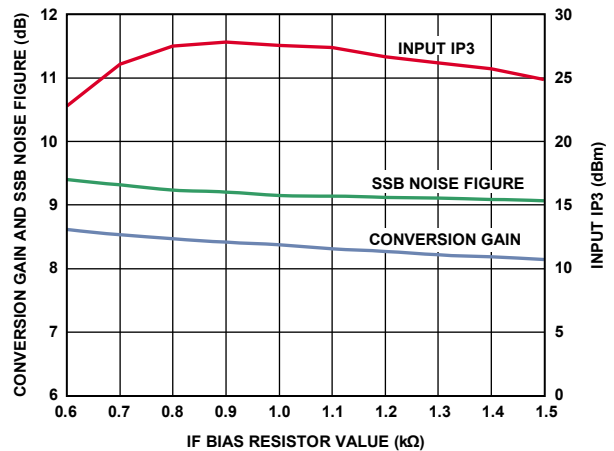


Figure 44. Power Conversion Gain, SSB Noise Figure, and Input IP3 vs. IF Bias Resistor Value

### 3.3 V PERFORMANCE

$V_S = 3.3\text{ V}$ ,  $I_S = 125\text{ mA}$ ,  $T_A = 25^\circ\text{C}$ ,  $f_{RF} = 1950\text{ MHz}$ ,  $f_{LO} = 1750\text{ MHz}$ , LO power = 0 dBm,  $R_9 = 226\ \Omega$ ,  $R_{14} = 604\ \Omega$ ,  $V_{GS0} = V_{GS1} = 0\text{ V}$ , and  $Z_O = 50\ \Omega$ , unless otherwise noted.

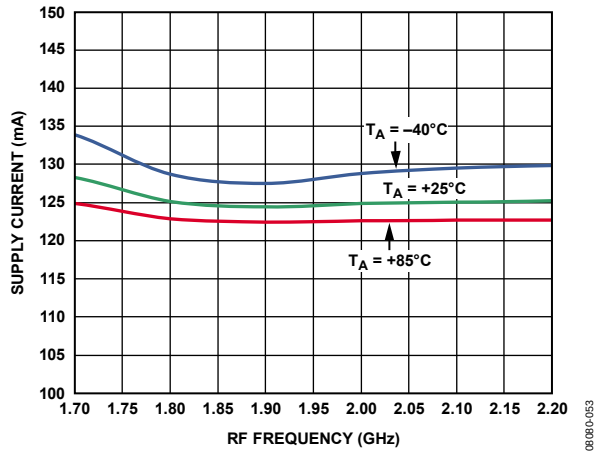


Figure 45. Supply Current vs. RF Frequency at 3.3 V

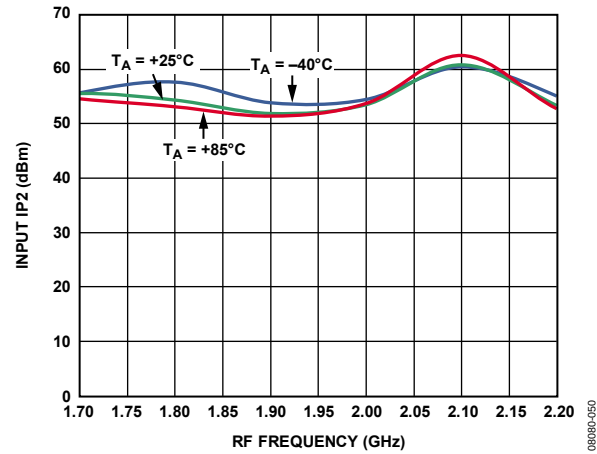


Figure 48. Input IP2 vs. RF Frequency at 3.3 V

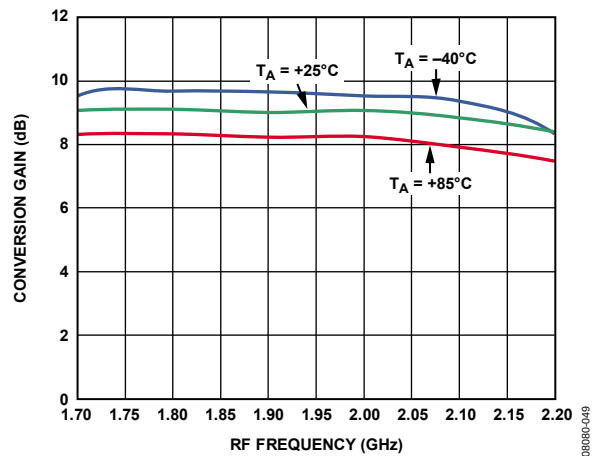


Figure 46. Power Conversion Gain vs. RF Frequency at 3.3 V

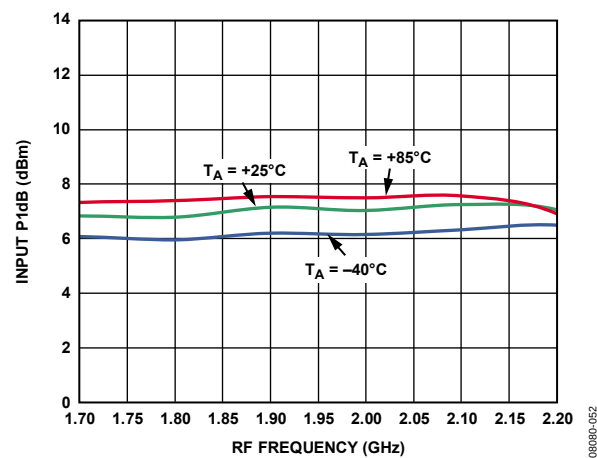


Figure 49. Input P1dB vs. RF Frequency at 3.3 V

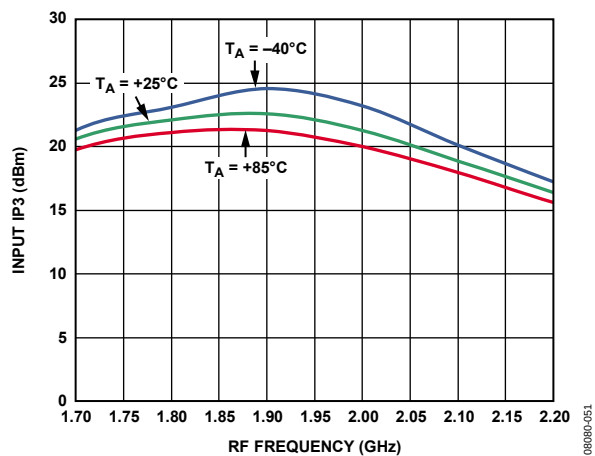


Figure 47. Input IP3 vs. RF Frequency at 3.3 V

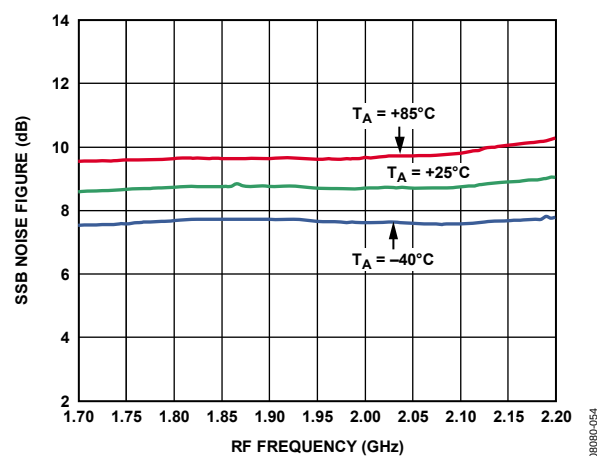


Figure 50. SSB Noise Figure vs. RF Frequency at 3.3 V

## CIRCUIT DESCRIPTION

The ADL5355 consists of two primary components: the radio frequency (RF) subsystem and the local oscillator (LO) subsystem. The combination of design, process, and packaging technology allows the functions of these subsystems to be integrated into a single die, using mature packaging and interconnection technologies to provide a high performance, low cost design with excellent electrical, mechanical, and thermal properties. In addition, the need for external components is minimized, optimizing cost and size.

The RF subsystem consists of an integrated, low loss RF balun, passive MOSFET mixer, sum termination network, and IF amplifier.

The LO subsystem consists of an SPDT-terminated FET switch and a three-stage limiting LO amplifier. The purpose of the LO subsystem is to provide a large, fixed amplitude, balanced signal to drive the mixer independent of the level of the LO input.

A block diagram of the device is shown in Figure 51.

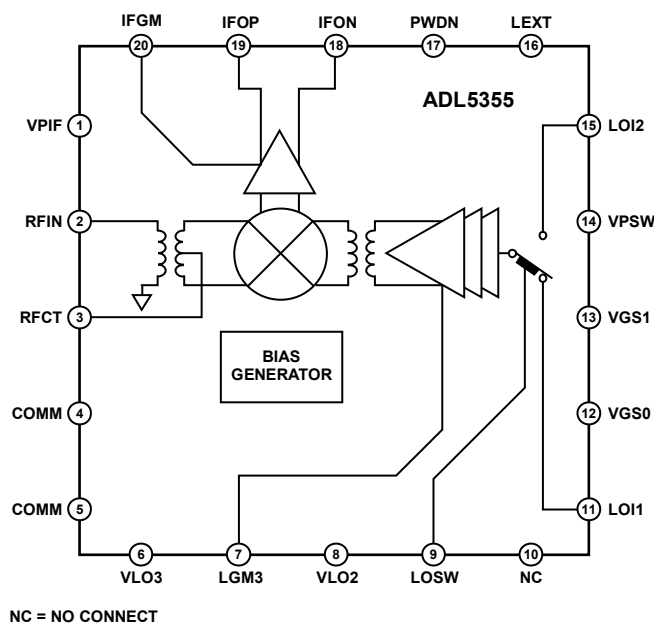


Figure 51. Simplified Schematic

## RF SUBSYSTEM

The single-ended, 50  $\Omega$  RF input is internally transformed to a balanced signal using a low loss (<1 dB) unbalanced-to-balanced (balun) transformer. This transformer is made possible by an extremely low loss metal stack, which provides both excellent balance and dc isolation for the RF port. Although the port can be dc connected, it is recommended that a blocking capacitor be used to avoid running excessive dc current through the part. The RF balun can easily support an RF input frequency range of 1200 MHz to 2500 MHz.

The resulting balanced RF signal is applied to a passive mixer that commutates the RF input with the output of the LO subsystem. The passive mixer is essentially a balanced, low loss switch that adds minimum noise to the frequency translation. The only noise contribution from the mixer is due to the resistive loss of the switches, which is in the order of a few ohms.

As the mixer is inherently broadband and bidirectional, it is necessary to properly terminate all the idler ( $M \times N$  product) frequencies generated by the mixing process. Terminating the mixer avoids the generation of unwanted intermodulation products and reduces the level of unwanted signals at the input of the IF amplifier, where high peak signal levels can compromise the compression and intermodulation performance of the system. This termination is accomplished by the addition of a sum network between the IF amplifier and the mixer and also in the feedback elements in the IF amplifier.

The IF amplifier is a balanced feedback design that simultaneously provides the desired gain, noise figure, and input impedance that is required to achieve the overall performance. The balanced open-collector output of the IF amplifier, with impedance modified by the feedback within the amplifier, permits the output to be connected directly to a high impedance filter, differential amplifier, or an analog-to-digital input while providing optimum second-order intermodulation suppression. The differential output impedance of the IF amplifier is approximately 200  $\Omega$ . If operation in a 50  $\Omega$  system is desired, the output can be transformed to 50  $\Omega$  by using a 4:1 transformer.

The intermodulation performance of the design is generally limited by the IF amplifier. The IP3 performance can be optimized by adjusting the IF current with an external resistor. Figure 41, Figure 43, and Figure 44 illustrate how various IF and LO bias resistors affect the performance with a 5 V supply. Additionally, dc current can be saved by increasing either or both resistors. It is permissible to reduce the dc supply voltage to as low as 3.3 V, further reducing the dissipated power of the part. (Note that no performance enhancement is obtained by reducing the value of these resistors and excessive dc power dissipation may result.)



## LO SUBSYSTEM

The LO amplifier is designed to provide a large signal level to the mixer to obtain optimum intermodulation performance. The resulting amplifier provides extremely high performance centered on an operating frequency of 1700 MHz. The best operation is achieved with either low-side LO injection for RF signals in the 1700 MHz to 2500 MHz range or high-side injection for RF signals in the 1200 MHz to 1700 MHz range. Operation outside these ranges is permissible, and conversion gain is extremely wideband, easily spanning 1200 MHz to 2500 MHz, but intermodulation is optimal over the aforementioned ranges.

The ADL5355 has two LO inputs permitting multiple synthesizers to be rapidly switched with extremely short switching times (<40 ns) for frequency agile applications. The two inputs are applied to a high isolation SPDT switch that provides a constant input impedance, regardless of whether the port is selected, to avoid pulling the LO sources. This multiple section switch also ensures high isolation to the off input, minimizing any leakage from the unwanted LO input that may result in undesired IF responses.

The single-ended LO input is converted to a fixed amplitude differential signal using a multistage, limiting LO amplifier. This results in consistent performance over a range of LO input power. Optimum performance is achieved from -6 dBm to +10 dBm, but the circuit continues to function at considerably lower levels of LO input power.

The performance of this amplifier is critical in achieving a high intercept passive mixer without degrading the noise floor of the system. This is a critical requirement in an interferer rich environment, such as cellular infrastructure, where blocking interferers can limit mixer performance. The bandwidth of the intermodulation performance is somewhat influenced by the current in the LO amplifier chain. For dc current sensitive applications, it is permissible to reduce the current in the LO amplifier by raising the value of the external bias control resistor. For dc current critical applications, the LO chain can operate with a supply voltage as low as 3.3 V, resulting in substantial dc power savings.

In addition, when operating with supply voltages below 3.6 V, the ADL5355 has a power-down mode that permits the dc current to drop to <200  $\mu$ A.

All of the logic inputs are designed to work with any logic family that provides a Logic 0 input level of less than 0.4 V and a Logic 1 input level that exceeds 1.4 V. All logic inputs are high impedance up to Logic 1 levels of 3.3 V. At levels exceeding 3.3 V, protection circuitry permits operation up to 5.5 V, although a small bias current is drawn.

All pins, including the RF pins, are ESD protected and have been tested up to a level of 1500 V HBM and 500 V CDM.

## APPLICATIONS INFORMATION

### BASIC CONNECTIONS

The ADL5355 mixer is designed to downconvert radio frequencies (RF) primarily between 1200 MHz and 2500 MHz to lower intermediate frequencies (IF) between 30 MHz and 450 MHz. Figure 52 depicts the basic connections of the mixer. It is recommended to ac-couple RF and LO input ports to prevent non-zero dc voltages from damaging the RF balun or LO input circuit. The RFIN capacitor value of 3 pF is recommended to provide the optimized RF input return loss for the desired frequency band.

### IF PORT

The mixer differential IF interface requires pull-up choke inductors to bias the open-collector outputs and to set the output match. The shunting impedance of the choke inductors used to couple dc current into the IF amplifier should be selected to provide the desired output return loss.

The real part of the output impedance is approximately 200  $\Omega$ , as seen in Figure 30, which matches many commonly used SAW filters without the need for a transformer. This results in a voltage conversion gain that is approximately 6 dB higher than the power conversion gain, as shown in Table 2. When a 50  $\Omega$  output impedance is needed, use a 4:1 impedance transformer, as shown in Figure 52.

### BIAS RESISTOR SELECTION

Two external resistors,  $R_{BIAS\ IF}$  and  $R_{BIAS\ LO}$ , are used to adjust the bias current of the integrated amplifiers at the IF and LO terminals. It is necessary to have a sufficient amount of current to bias both the internal IF and LO amplifiers to optimize dc current vs. optimum IIP3 performance. Figure 41, Figure 43, and Figure 44 provide the reference for the bias resistor selection when lower power consumption is considered at the expense of conversion gain and IP3 performance.

### MIXER VGS CONTROL DAC

The ADL5355 features two logic control pins, VGS0 (Pin 12) and VGS1 (Pin 13), that allow programmability for internal gate-to-source voltages for optimizing mixer performance over desired frequency bands. The evaluation board defaults both VGS0 and VGS1 to ground. Power conversion gain, IIP3, NF, and IP1dB can be optimized, as is shown in Figure 39 and Figure 40.

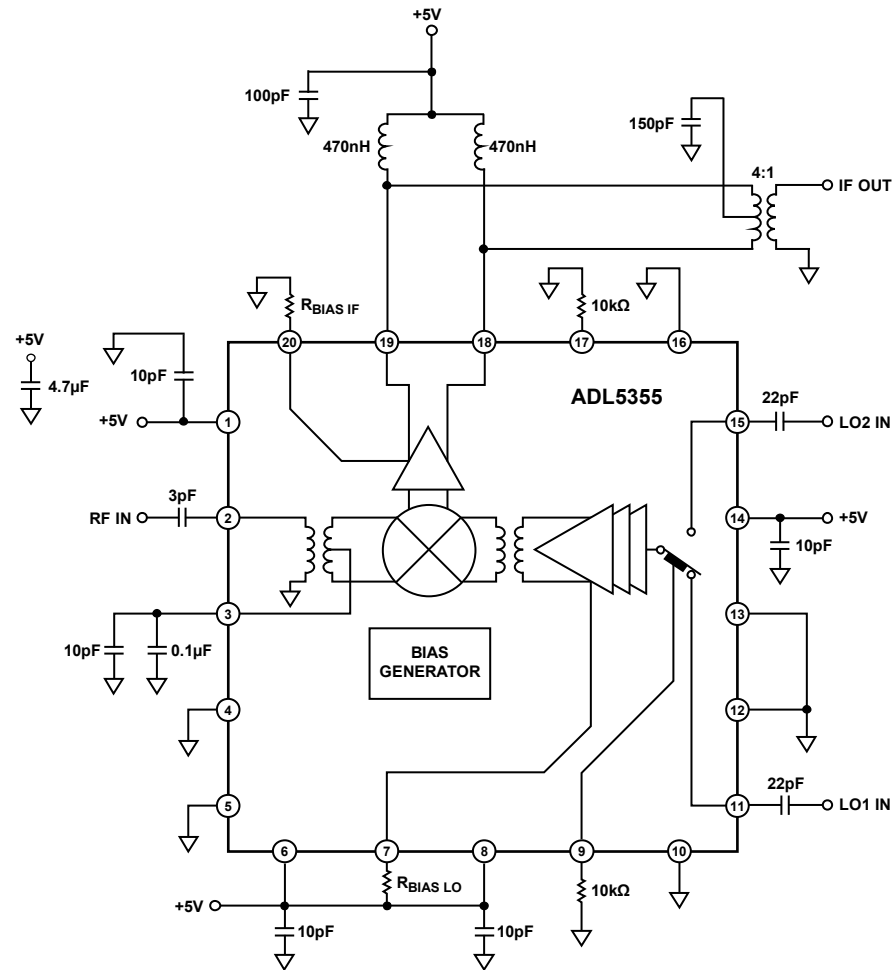


Figure 52. Typical Application Circuit

08650-005

## EVALUATION BOARD

An evaluation board is available for the family of double balanced mixers. The standard evaluation board schematic is shown in Figure 53. The evaluation board is fabricated using Rogers® RO3003 material. Table 8 describes the various configuration options of the evaluation board. Evaluation board layout is shown in Figure 54 to Figure 57.

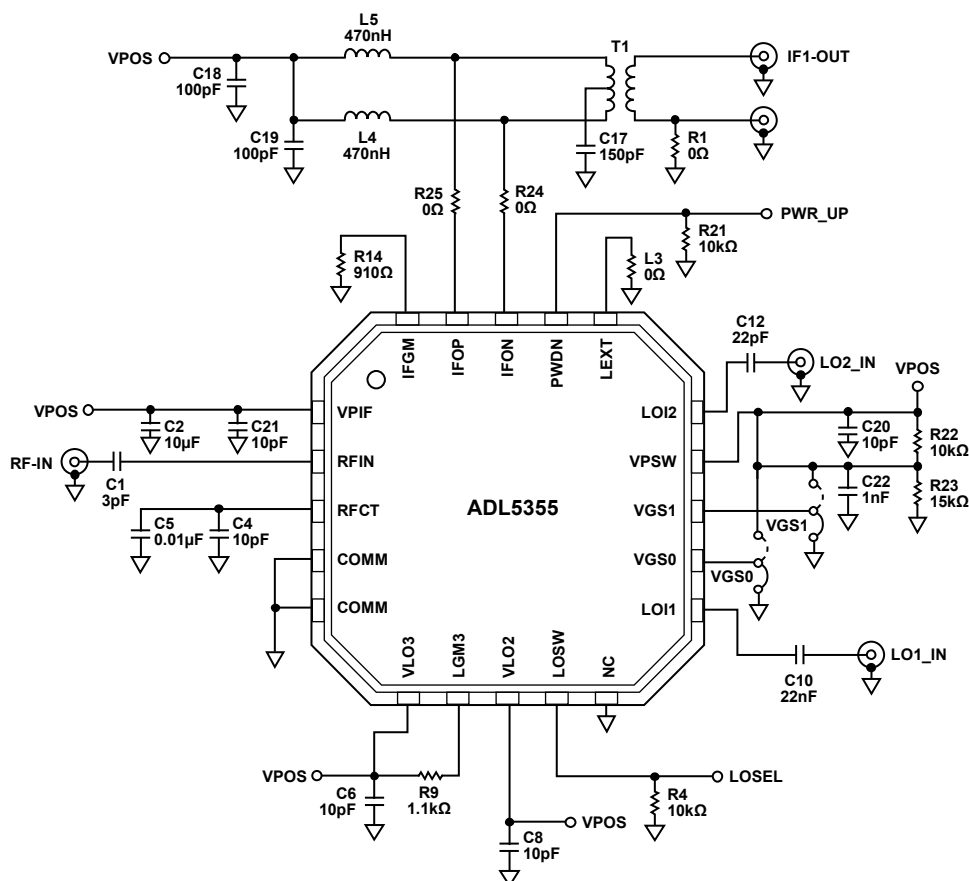


Figure 53. Evaluation Board Schematic

08080-542

**Table 8. Evaluation Board Configuration**

| Components                             | Description                                                                                                                                                                                                                                                                                                                                                                      | Default Conditions                                                                                                                                                                                                         |
|----------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| C2, C6, C8, C18, C19, C20, C21         | Power Supply Decoupling. Nominal supply decoupling consists of a 10 $\mu$ F capacitor to ground in parallel with a 10 pF capacitor to ground positioned as close to the device as possible.                                                                                                                                                                                      | C2 = 10 $\mu$ F (size 0603),<br>C6, C8, C20, C21 = 10 pF (size 0402),<br>C18, C19 = 100 pF (size 0402)                                                                                                                     |
| C1, C4, C5                             | RF Input Interface. The input channels are ac-coupled through C1. C4 and C5 provide bypassing for the center taps of the RF input baluns.                                                                                                                                                                                                                                        | C1 = 3 pF (size 0402), C4 = 10 pF (size 0402),<br>C5 = 0.01 $\mu$ F (size 0402)                                                                                                                                            |
| T1, C17, L4, L5, R1, R24, R25          | IF Output Interface. The open-collector IF output interfaces are biased through pull-up choke inductors L4 and L5. T1 is a 4:1 impedance transformer used to provide a single-ended IF output interface, with C17 providing center-tap bypassing. Remove R1 for balanced output operation.                                                                                       | T1 = TC4-1W+ (Mini-Circuits),<br>C17 = 150 pF (size 0402),<br>L4, L5 = 470 nH (size 1008),<br>R1, R24, R25 = 0 $\Omega$ (size 0402)                                                                                        |
| C10, C12, R4                           | LO Interface. C10 and C12 provide ac coupling for the LO1_IN and LO2_IN local oscillator inputs. LOSEL selects the appropriate LO input for both mixer cores. R4 provides a pull-down to ensure that LO1_IN is enabled when the LOSEL test point is logic low. LO2_IN is enabled when LOSEL is pulled to logic high.                                                             | C10, C12 = 22 pF (size 0402),<br>R4 = 10 k $\Omega$ (size 0402)                                                                                                                                                            |
| R21                                    | PWDN Interface. R21 pulls the PWDN logic low and enables the device. The PWR_UP test point allows the PWDN interface to be exercised using the external logic generator. Grounding the PWDN pin for nominal operation is allowed. Using the PWDN pin when supply voltages exceed 3.3 V is not allowed.                                                                           | R21 = 10 k $\Omega$ (size 0402)                                                                                                                                                                                            |
| C22, L3, R9, R14, R22, R23, VGS0, VGS1 | Bias Control. R22 and R23 form a voltage divider to provide 3 V for logic control, bypassed to ground through C22. VGS0 and VGS1 jumpers provide programmability at the VGS0 and VGS1 pins. It is recommended to pull these two pins to ground for nominal operation. R9 sets the bias point for the internal LO buffers. R14 sets the bias point for the internal IF amplifier. | C22 = 1 nF (size 0402), L3 = 0 $\Omega$ (size 0603),<br>R9 = 1.1 k $\Omega$ (size 0402), R14 = 910 $\Omega$ (size 0402),<br>R22 = 10 k $\Omega$ (size 0402), R23 = 15 k $\Omega$ (size 0402),<br>VGS0 = VGS1 = 3-pin shunt |

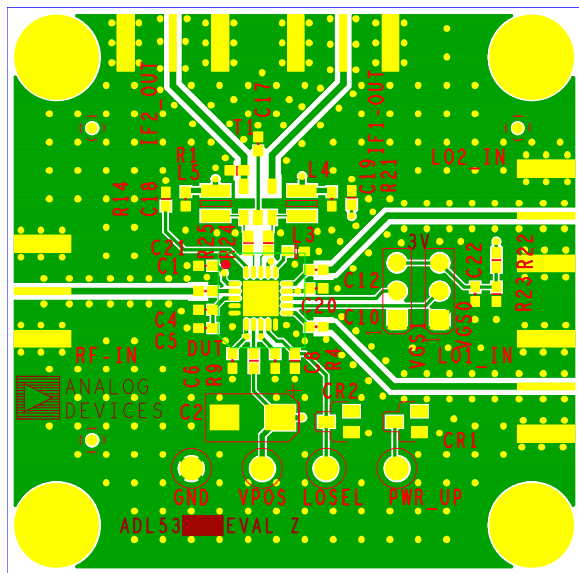


Figure 54. Evaluation Board Top Layer

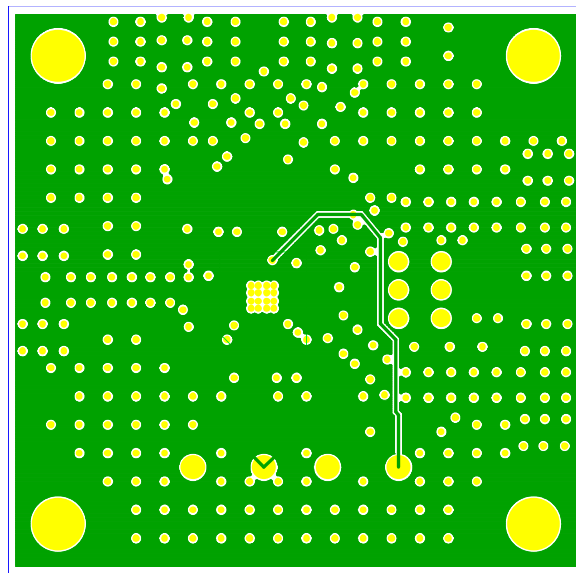


Figure 56. Evaluation Board Power Plane, Internal Layer 2

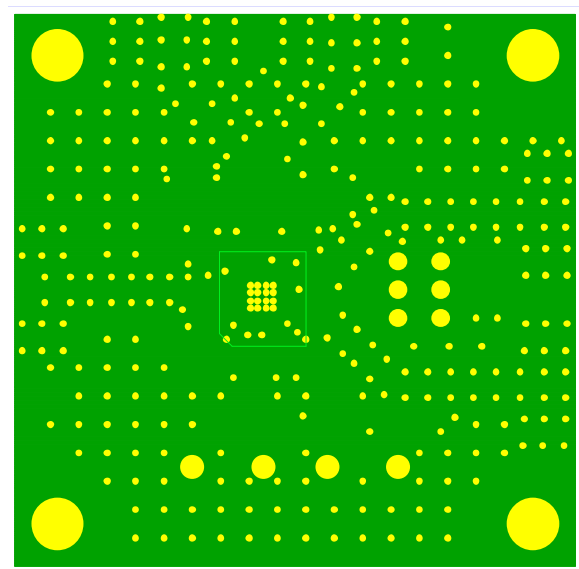


Figure 55. Evaluation Board Ground Plane, Internal Layer 1

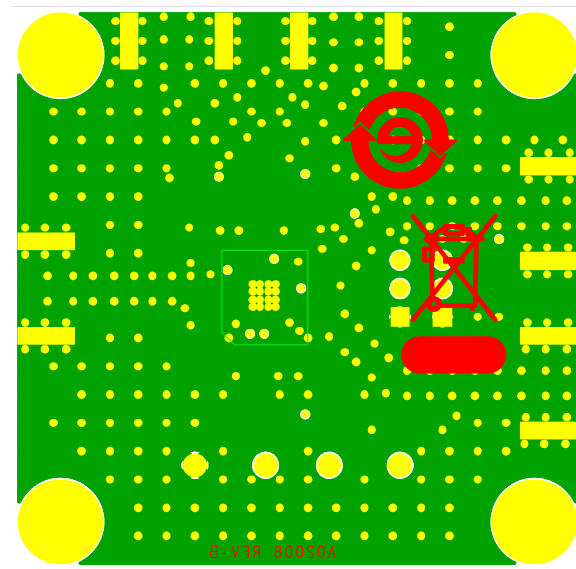
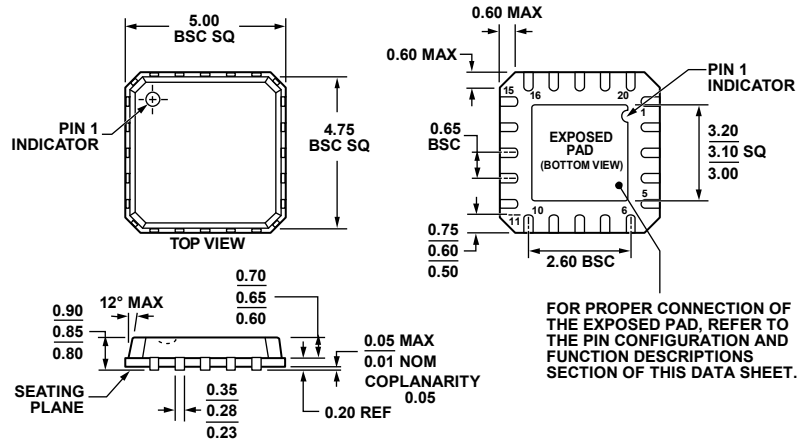


Figure 57. Evaluation Board Bottom Layer

## OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-220-VHHC

Figure 58. 20-Lead Lead Frame Chip Scale Package [LFCSP\_VQ]  
5 mm × 5 mm Body, Very Thin Quad (CP-20-5)  
Dimensions shown in millimeters

## ORDERING GUIDE

| Model                       | Temperature Range | Package Description                              | Package Option | Ordering Quantity       |
|-----------------------------|-------------------|--------------------------------------------------|----------------|-------------------------|
| ADL5355ACPZ-R7 <sup>1</sup> | −40°C to +85°C    | 20-Lead Lead Frame Chip Scale Package [LFCSP_VQ] | CP-20-5        | 1,500, 7" Tape and Reel |
| ADL5355ACPZ-WP <sup>1</sup> | −40°C to +85°C    | 20-Lead Lead Frame Chip Scale Package [LFCSP_VQ] | CP-20-5        | 36, Waffle Pack         |
| ADL5355-EVALZ <sup>1</sup>  |                   | Evaluation Board                                 |                | 1                       |

<sup>1</sup> Z = RoHS Compliant Part.

**ADL5355**

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## NOTES